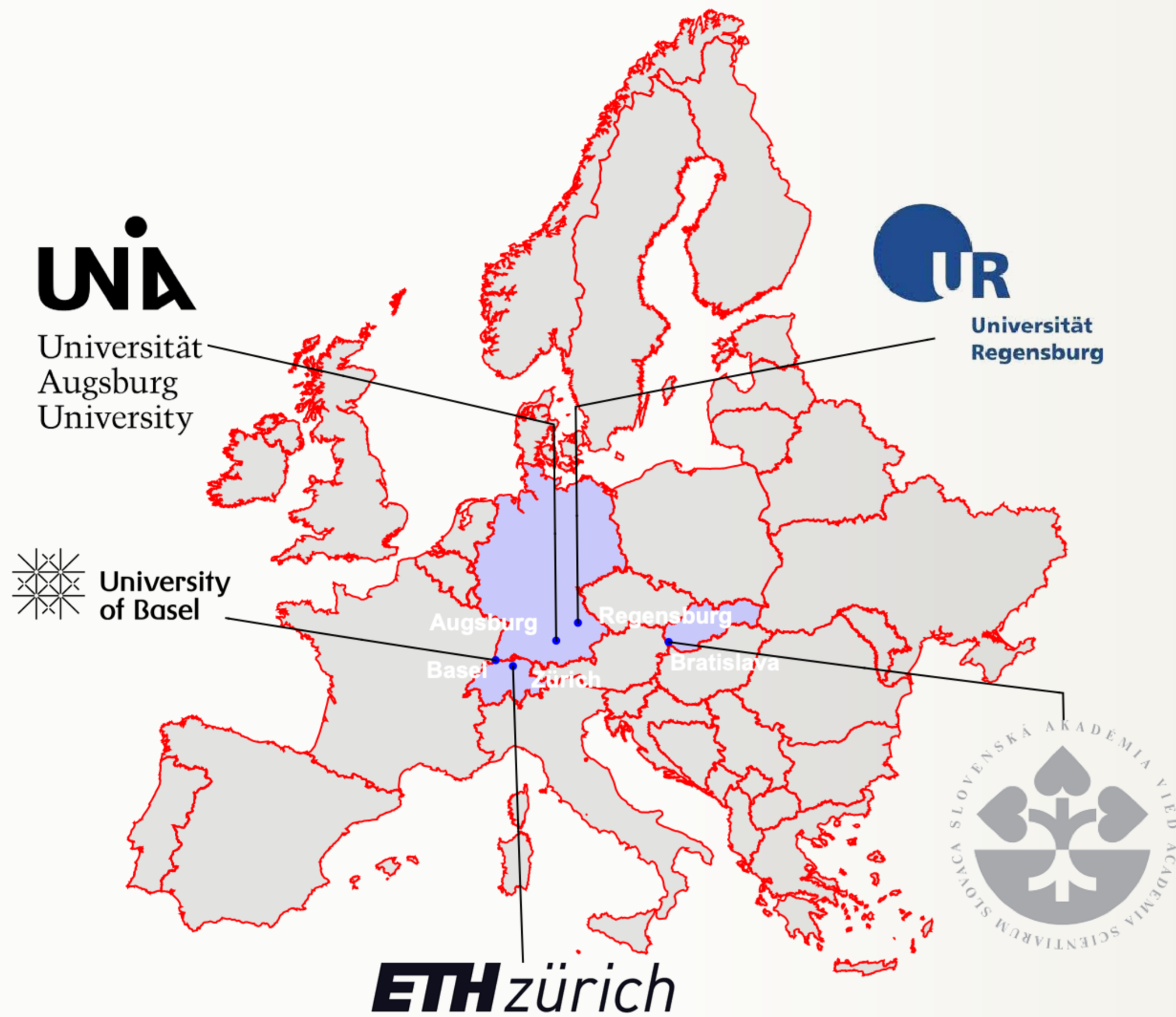
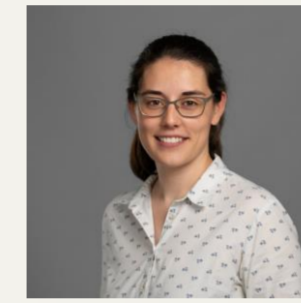


Germanium MOSFETs for quantum computation

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grand goals

**high-quality 2DHG
 at the Ge/oxide interface**

**scalable Ge-MOSFET
 devices**

**competitive Ge-MOSFET
 hole-spin qubits**

